

2.5V Reference

DESCRIPTION

The RH1009 is a general purpose 2.5V shunt regulator diode designed to operate over a wide current range while maintaining good stability with time and temperature. The adjust terminal allows either temperature coefficient to be minimized or the reference voltage to be adjusted without changing the temperature coefficient. Because it operates as a shunt regulator it can be used equally well as a positive or negative reference.

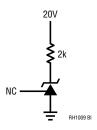
The wafer lots are processed to Linear Technology's inhouse Class S flow to yield circuits usable in stringent military applications.

ABSOLUTE MAXIMUM RATINGS

	20mA
	10mA
-55°C to	125°C
-65°C to	150°C
	300°C
	-55°C to

∠7, LTC and LT are registered trademarks of Linear Technology Corporation.

BURN-IN CIRCUIT



PACKAGE/ORDER INFORMATION

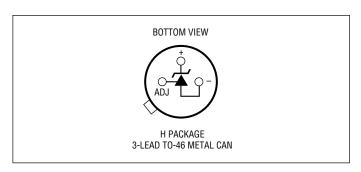


TABLE 1: ELECTRICAL CHARACTERISTICS (Preirradiation)

SYMBOL	PARAMETER	CONDITIONS	NOTES		j = 25° TYP	C MAX	SUB- Group	-55°C MIN	150°C Max	SUB- Group	UNITS
V_Z	Reverse Breakdown Voltage	I _R = 1mA		2.495		2.505	1				V
$\frac{\Delta V_Z}{\Delta I_R}$	Reverse Breakdown Voltage Change with Current	$400\mu\text{A} \le I_{R} \le 10\text{mA}$				6	1		10	2,3	mV
r_Z	Reverse Dynamic Impedance	I _R = 1mA	1			0.6			1		Ω
ΔV_Z	Temperature Stability		1						15		mV
$\frac{\Delta V_Z}{\Delta Time}$	Long Term Stability	$T_A = 25^{\circ}C \pm 0.1^{\circ}C$, $I_R = 1 \text{mA}$			20						ppm/kHr

TABLE 1A: ELECTRICAL CHARACTERISTICS (Postirradiation) (Note 2)

				10KRAD(Si) 20KRAD(Si)		50KRAD(Si)		100KRAD(Si)		200KRAD(Si)				
SYMBOL	PARAMETER	CONDITIONS	NOTES	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
V _Z	Reverse Breakdown Voltage	I _R = 1mA		2.495	2.505	2.495	2.505	2.495	2.505	2.495	2.505	2.495	2.505	V
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse Breakdown Voltage Change with Current	$400\mu\text{A} \le I_{R} \le 10\text{mA}$			6		6		8		10		12	mV
r _Z	Reverse Dynamic Impedance	I _R = 1mA	1		0.6		0.6		0.8		1.0		1.4	Ω

Note 1: Guaranteed by design, characterization or correlation to other tested parameters.

Note 2: $T_A = 25^{\circ}C$ unless otherwise noted.

TOTAL DOSE BIAS CIRCUIT



TABLE 2: ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUP
Final Electrical Test Requirements (Method 5004)	1*,2,3
Group A Test Requirements (Method 5005)	1,2,3
Group C and D End Point Electrical Parameters (Method 5005)	1

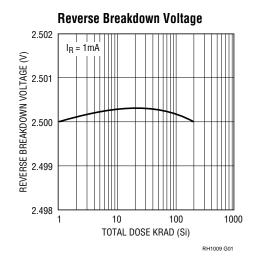
^{*} PDA Applies to subgroup 1. See PDA Test Notes.

PDA Test Notes

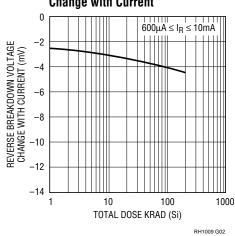
The PDA is specified as 5% based on failures from group A, subgroup 1, tests after cooldown as the final electrical test in accordance with method 5004 of MIL-STD-883 Class B. The verified failures of group A, subgroup 1, after burn-in divided by the total number of devices submitted for burn-in in that lot shall be used to determine the percent for the lot.

Linear Technology Corporation reserves the right to test to tighter limits than those given.

TYPICAL PERFORMANCE CHARACTERISTICS



Reverse Breakdown Voltage Change with Current



I.D. No. 66-10-0174 Rev. B 0497